

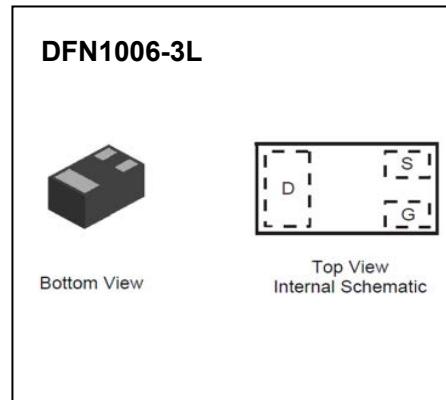


JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

DFN1006-3L Plastic-Encapsulate MOSFETs

CJBA7002K N-Channel MOSFET

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | I_D |
|---------------|-----------------|-------|
| 60V | 1.5Ω@10V | 0.41A |
| | 1.8Ω@4.5V | |



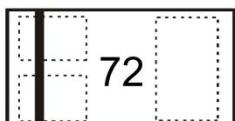
FEATURE

- Low On-Resistance
- Low Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate

APPLICATION

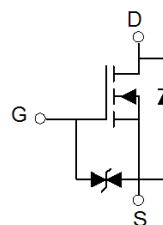
- Load Switch
- Portable Applications
- Power Management Functions

MARKING:



Top View
Bar Denotes Gate
and Source Side

Equivalent Circuit



ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|-------------------------------|----------|------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current | I_D | 0.41 | A |
| | | 0.30 | |
| Pulsed Drain Current | I_{DM} | 1.2 | A |
| Power Dissipation | P_D^{\circledast} | 275 | mW |
| Thermal Resistance from Junction to Ambient | $R_{\theta JA}^{\circledast}$ | 455 | °C/W |
| Operation Junction and Storage Temperature Range | T_J, T_{STG} | -55~+150 | °C |

MOSFET ELECTRICAL CHARACTERISTICS

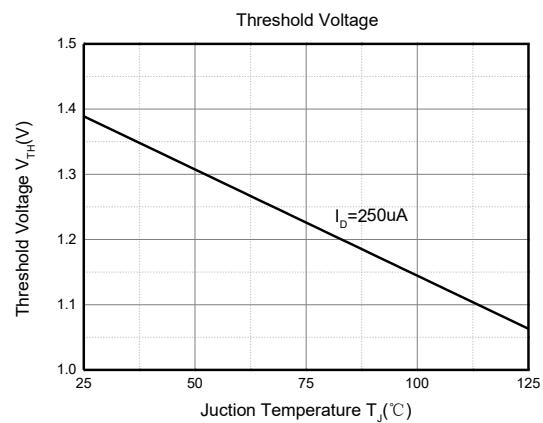
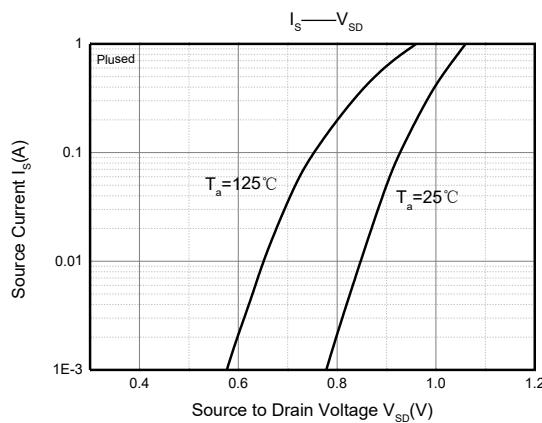
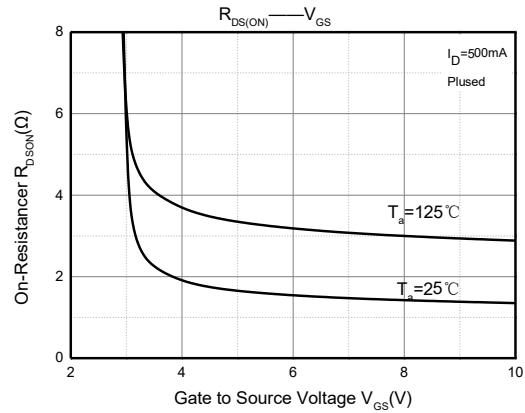
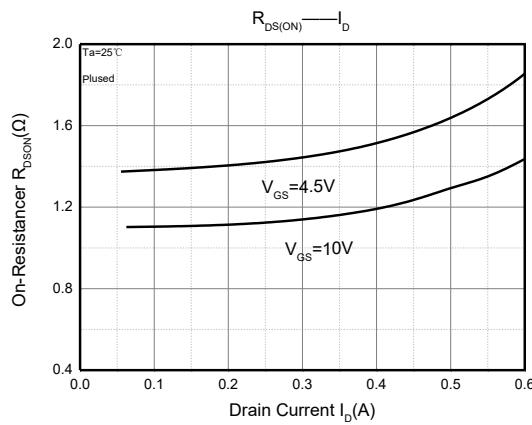
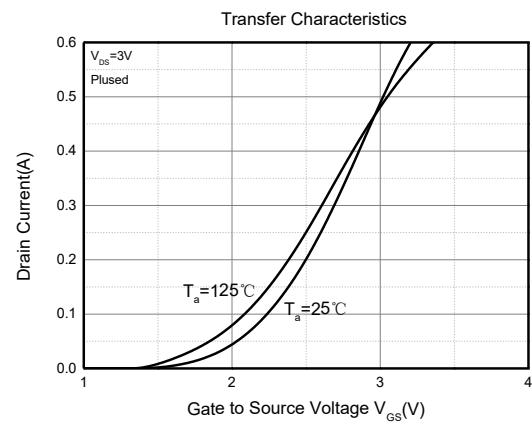
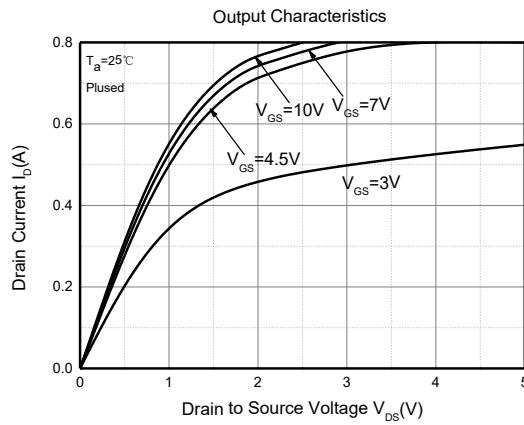
MOSFET ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Test Condition | Min | Type | Max | Unit |
|---|-----------------------------|---|-----|-------|----------|---------------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$ | 60 | | | V |
| Zero gate voltage drain current | I_{DSS} | $V_{\text{DS}} = 60\text{V}, V_{\text{GS}} = 0\text{V}$ | | | 100 | nA |
| Gate-body leakage current | I_{GSS} | $V_{\text{GS}} = \pm 20\text{V}, V_{\text{DS}} = 0\text{V}$ | | | ± 10 | μA |
| | | $V_{\text{GS}} = \pm 5\text{V}, V_{\text{DS}} = 0\text{V}$ | | | ± 1 | |
| Gate threshold voltage | $V_{\text{GS}(\text{th})}$ | $V_{\text{DS}} = V_{\text{GS}}, I_D = 250\mu\text{A}$ | 1.3 | 1.4 | 2.3 | V |
| Drain-source on-resistance ^① | $R_{\text{DS}(\text{on})}$ | $V_{\text{GS}} = 10\text{V}, I_D = 40\text{mA}$ | | 1.2 | 1.5 | Ω |
| | | $V_{\text{GS}} = 4.5\text{V}, I_D = 35\text{mA}$ | | 1.3 | 1.8 | |
| Forward transconductance ^① | g_{fs} | $V_{\text{DS}} = 5\text{V}, I_D = 40\text{mA}$ | 100 | | | mS |
| Diode forward voltage | V_{SD} | $V_{\text{GS}} = 0\text{V}, I_S = 300\text{mA}$ | | 0.84 | 1.1 | V |
| Dynamic characteristics | | | | | | |
| Input Capacitance ^② | C_{iss} | $V_{\text{DS}} = 40\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$ | | 41 | 80 | pF |
| Output Capacitance ^② | C_{oss} | | | 3.6 | 7 | |
| Reverse Transfer Capacitance ^② | C_{rss} | | | 2.9 | 5.6 | |
| Gate resistance | R_g | $V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$ | | 81 | 200 | Ω |
| Total Gate Charge | Q_g | $V_{\text{GS}} = 4.5\text{V}$ $V_{\text{GS}} = 10\text{V}$ $V_{\text{DS}} = 50\text{V}, I_D = 0.41\text{A}$ | | 0.72 | 1.5 | nC |
| Gate-Source Charge | Q_{gs} | | | 1.41 | 2.8 | |
| Gate-Drain Charge | Q_{gd} | | | 0.24 | 0.4 | |
| Turn-on delay time ^② | $t_{\text{d}(\text{on})}$ | | | 0.24 | 0.5 | |
| Turn-on rise time ^② | t_r | $V_{\text{DS}} = 30\text{V}, R_L = 50\Omega$ $V_{\text{GS}} = 10\text{V}, R_G = 6\Omega$ | | 3.98 | 10 | ns |
| Turn-off delay time ^② | $t_{\text{d}(\text{off})}$ | | | 4.95 | 10 | |
| Turn-off fall time ^② | t_f | | | 18.52 | 40 | |
| | | | | 11.94 | 25 | |

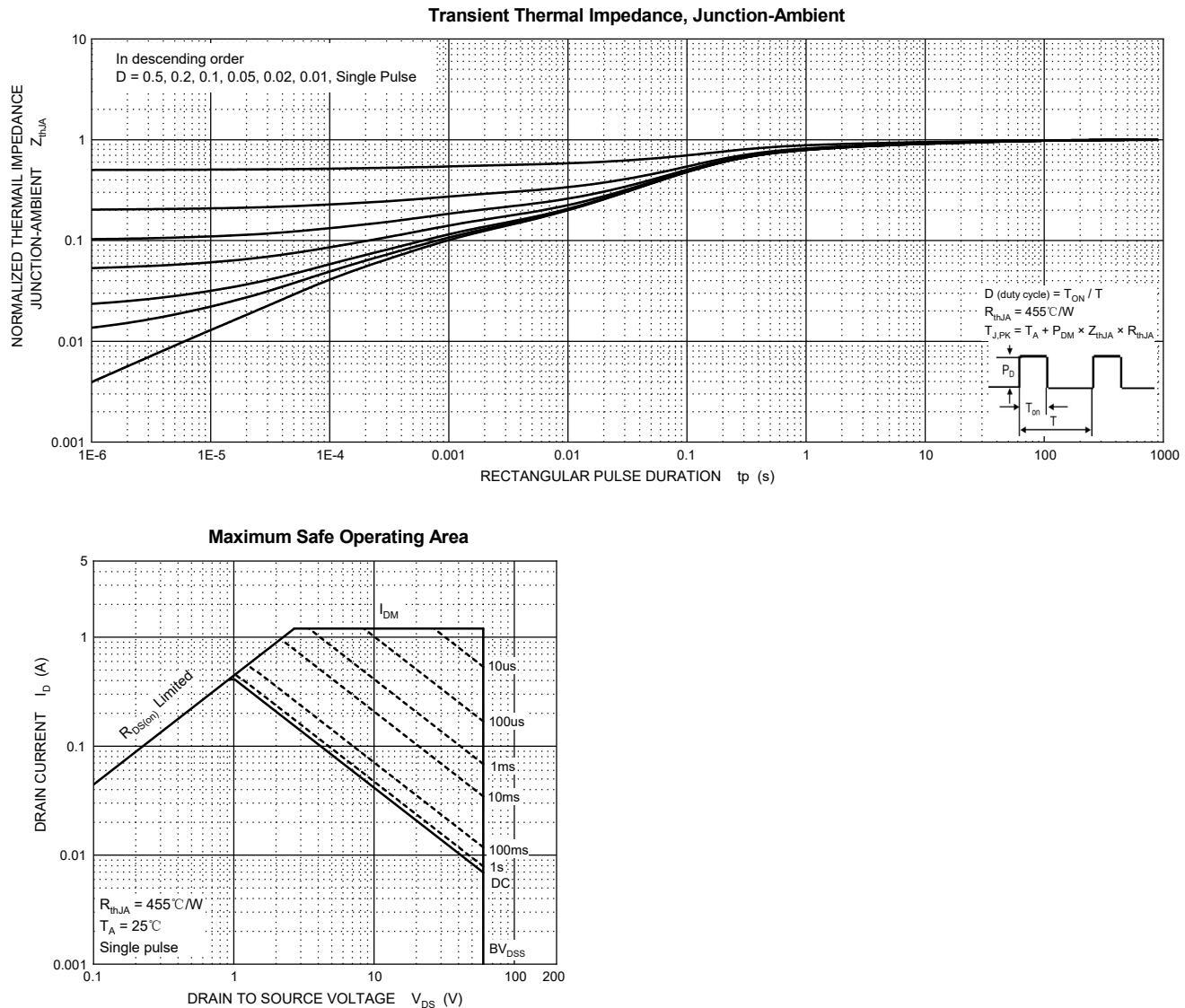
Notes:

- 1.Pulse Test : Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
- 2.These parameters have no way to verify.
- 3.Surface mounted on FR4 board using 1 square inch pad size, 1oz copper.

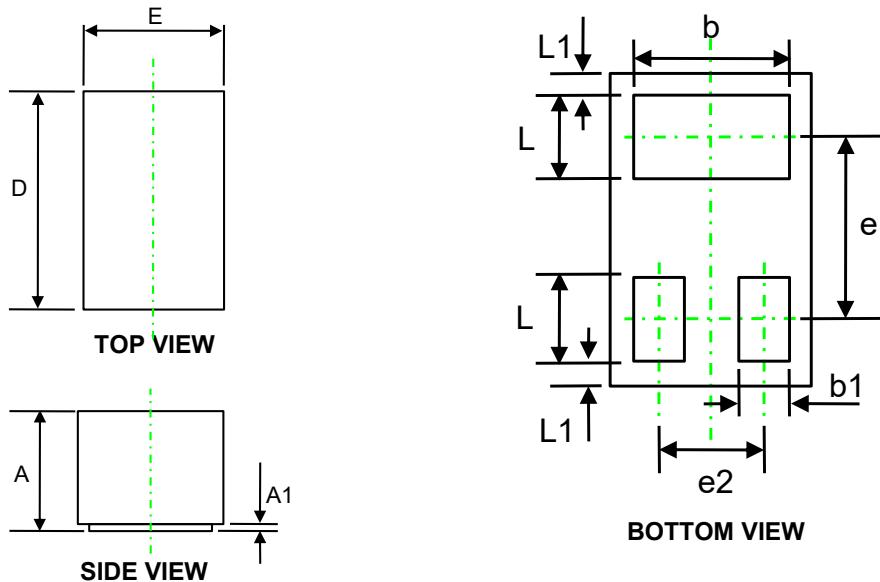
Typical Characteristics



Typical Characteristics

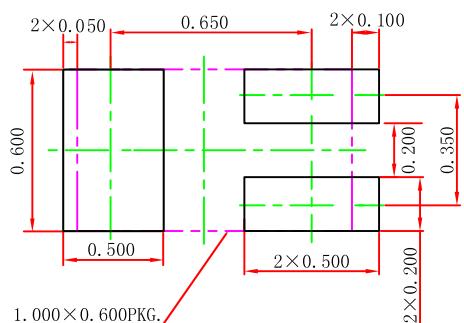


DFN1006-3L Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.400 | 0.550 | 0.016 | 0.022 |
| A1 | 0.000 | 0.050 | 0.000 | 0.002 |
| D | 0.950 | 1.050 | 0.037 | 0.041 |
| E | 0.550 | 0.650 | 0.022 | 0.026 |
| b | 0.450 | 0.550 | 0.018 | 0.022 |
| e | 0.650 REF. | | 0.026 REF. | |
| e2 | 0.350 REF. | | 0.014 REF. | |
| L1 | 0.050 REF. | | 0.002 REF. | |
| L | 0.200 | 0.300 | 0.008 | 0.012 |
| b1 | 0.100 | 0.200 | 0.004 | 0.008 |

DFN1006-3L Suggested Pad Layout



Note:

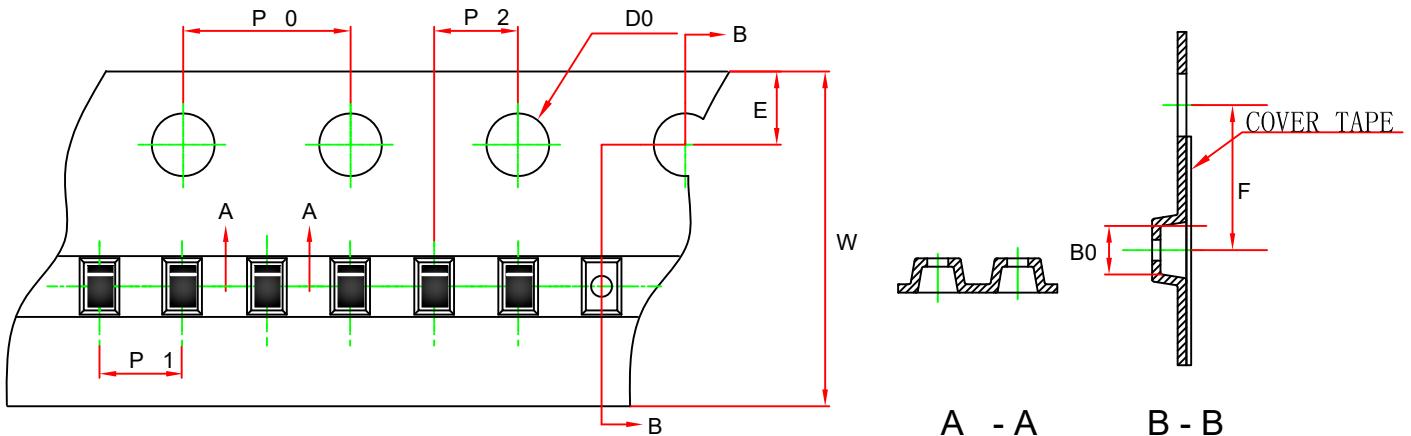
- Controlling dimension:in millimeters.
- General tolerance: ± 0.050 mm.
- The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

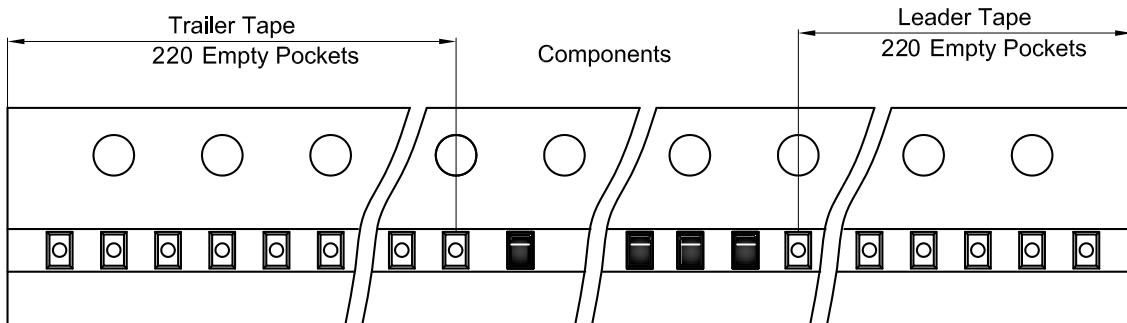
DFN1006-3L Tape and Reel

DFN1006-3L Embossed Carrier Tape

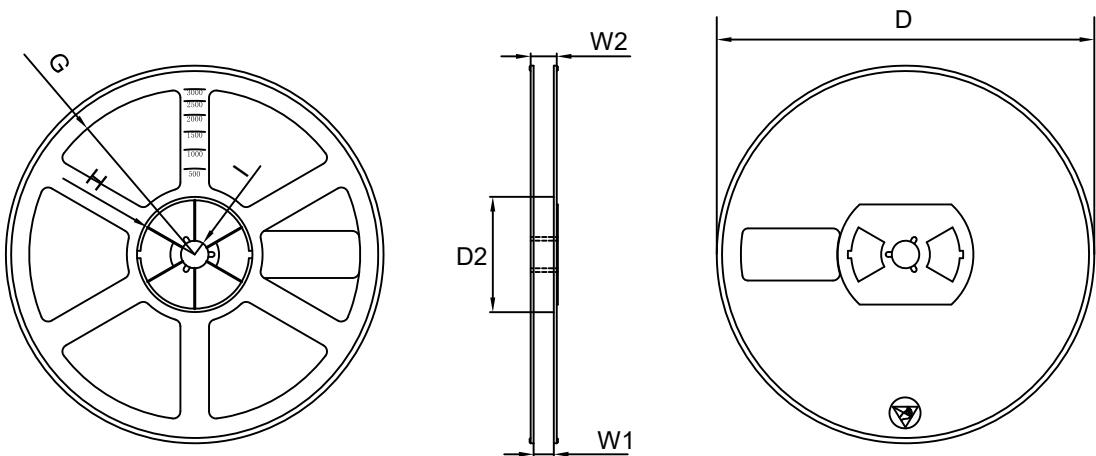


| Dimensions In Millimeters (mm) | | | | | | | | |
|--------------------------------|---------|--------|--------|--------|--------|--------|--------|--------|
| Pkg type | B0 | P0 | P1 | P2 | E | F | W | D0 |
| DFN1006-3L | 1.11 | 4.00 | 2.00 | 2.00 | 1.75 | 3.50 | 8.00 | 1.55 |
| Tolerance | +/-0.06 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.1 | +/-0.3 | +/-0.1 |

DFN1006-3L Tape Leader and Trailer



DFN1006-3L Reel



| Symbol | Dimensions In Millimeters (mm) | | | | | | |
|-----------|--------------------------------|-------|--------|-------|------|------|--------|
| | D | D2 | G | H | I | W1 | W2 |
| 7" Dia | Φ178.00 | 54.50 | R78.00 | R25.6 | R6.5 | 9.50 | 12.30 |
| Tolerance | +/-2 | +/-1 | +/-1 | +/-1 | +/-1 | +/-2 | +/-1.5 |

| REEL | Reel Size | Box | Box size(mm) | Carton | Carton Size(mm) |
|-----------|-----------|------------|--------------|------------|-----------------|
| 10000 pcs | 7 inch | 150000 pcs | 220×220×210 | 600000 pcs | 450×450×240 |